



SamHop Microelectronics Corp.



STT3418

Ver 1.0

N-Channel Logic Level Enhancement Mode Field Effect Transistor

PRODUCT SUMMARY		
VDSS	ID	RDS(ON) (mΩ) Max
30V	5A	39 @ VGS=10V 63 @ VGS=4.5V

FEATURES

- Super high dense cell design for low RDS(ON).
- Rugged and reliable.
- Surface Mount Package.



ABSOLUTE MAXIMUM RATINGS (TA=25°C unless otherwise noted)

Symbol	Parameter	Limit	Units
V _{DS}	Drain-Source Voltage	30	V
V _{GS}	Gate-Source Voltage	±20	V
I _D	Drain Current-Continuous ^a	5	A
	T _A =25°C		
	T _A =70°C	4	A
I _{DM}	-Pulsed ^b	20	A
E _{AS}	Single Pulse Avalanche Energy ^d	12	mJ
P _D	Maximum Power Dissipation ^a	3	W
	T _A =25°C		
	T _A =70°C	1.9	W
T _J , T _{STG}	Operating Junction and Storage Temperature Range	-55 to 150	°C

THERMAL CHARACTERISTICS

R _{θ JA}	Thermal Resistance, Junction-to-Ambient ^a	42	°C/W
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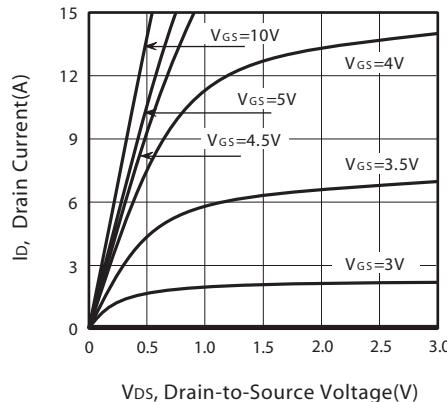
ELECTRICAL CHARACTERISTICS ($T_A=25^\circ C$ unless otherwise noted)

Symbol	Parameter	Conditions	Min	Typ	Max	Units
OFF CHARACTERISTICS						
BVDSS	Drain-Source Breakdown Voltage	$V_{GS}=0V, I_D=250\mu A$	30			V
IDS	Zero Gate Voltage Drain Current	$V_{DS}=24V, V_{GS}=0V$			1	μA
IGSS	Gate-Body Leakage Current	$V_{GS} = \pm 20V, V_{DS}=0V$			± 100	nA
ON CHARACTERISTICS						
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS}=V_{GS}, I_D=250\mu A$	1	1.7	3	V
RDS(ON)	Drain-Source On-State Resistance	$V_{GS}=10V, I_D=2.5A$		31	39	m ohm
		$V_{GS}=4.5V, I_D=2A$		47	63	m ohm
gFS	Forward Transconductance	$V_{DS}=10V, I_D=2.5A$		9		S
DYNAMIC CHARACTERISTICS ^c						
C _{ISS}	Input Capacitance	$V_{DS}=15V, V_{GS}=0V$ $f=1.0MHz$		351		pF
C _{OSS}	Output Capacitance			69		pF
C _{RSS}	Reverse Transfer Capacitance			52		pF
SWITCHING CHARACTERISTICS ^c						
t _{D(ON)}	Turn-On Delay Time	$V_{DD}=15V$ $I_D=1A$ $V_{GS}=10V$ $R_{GEN}=6\text{ ohm}$		8		ns
t _r	Rise Time			11.2		ns
t _{D(OFF)}	Turn-Off Delay Time			16.5		ns
t _f	Fall Time			4.6		ns
Q _g	Total Gate Charge	$V_{DS}=15V, I_D=2.5A, V_{GS}=10V$		5.8		nC
		$V_{DS}=15V, I_D=2.5A, V_{GS}=4.5V$		3.2		nC
Q _{gs}	Gate-Source Charge	$V_{DS}=15V, I_D=2.5A,$ $V_{GS}=10V$		1		nC
Q _{gd}	Gate-Drain Charge			1.8		nC
DRAIN-SOURCE DIODE CHARACTERISTICS AND MAXIMUM RATINGS						
V _{SD}	Diode Forward Voltage	$V_{GS}=0V, I_S=2.5A$		0.86	1.2	V
Notes						
a. Surface Mounted on FR4 Board, t < 10sec.						
b. Pulse Test: Pulse Width < 300us, Duty Cycle < 2%.						
c. Guaranteed by design, not subject to production testing.						
d. Starting $T_J=25^\circ C, L=0.5mH, V_{DD}=20V$. (See Figure13)						

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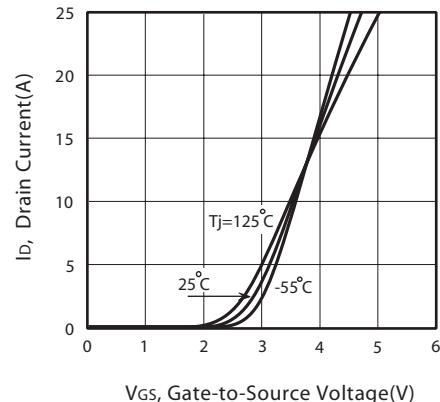
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V_{DS}, Drain-to-Source Voltage(V)

Figure 1. Output Characteristics



V_{GS}, Gate-to-Source Voltage(V)

Figure 2. Transfer Characteristics

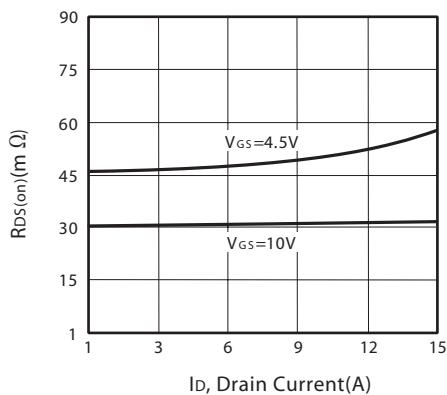


Figure 3. On-Resistance vs. Drain Current and Gate Voltage

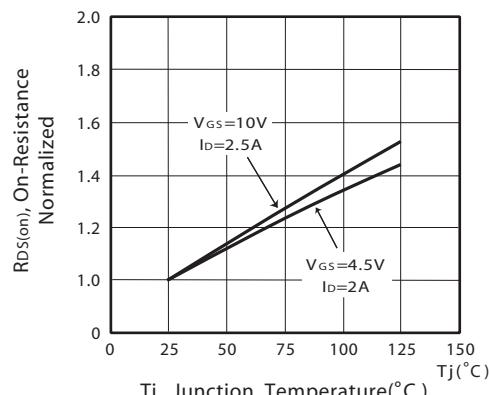


Figure 4. On-Resistance Variation with Drain Current and Temperature

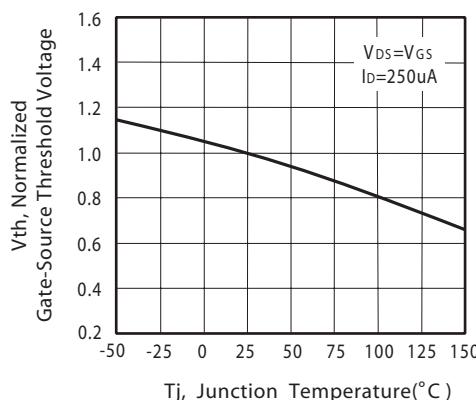


Figure 5. Gate Threshold Variation with Temperature

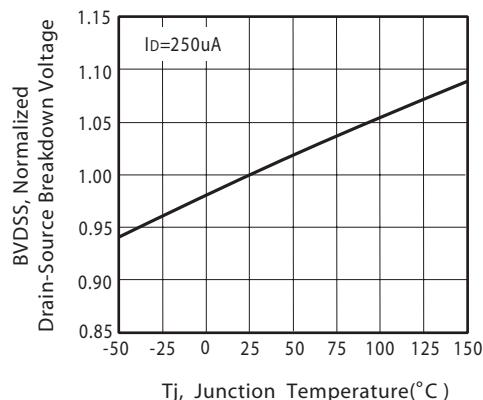
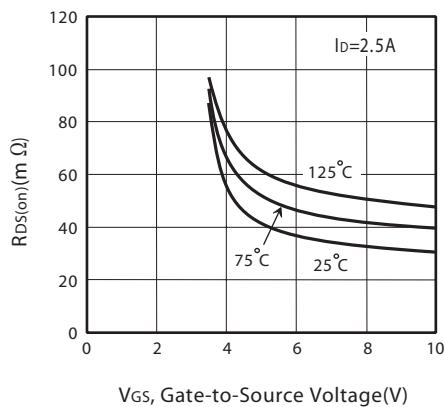


Figure 6. Breakdown Voltage Variation with Temperature

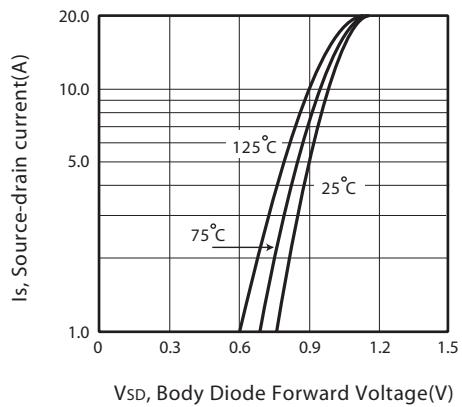
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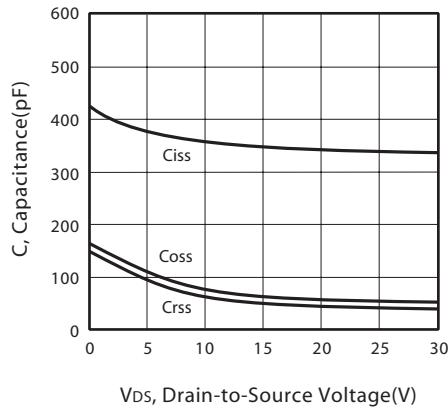
V_{GS}, Gate-to-Source Voltage(V)

Figure 7. On-Resistance vs. Gate-Source Voltage



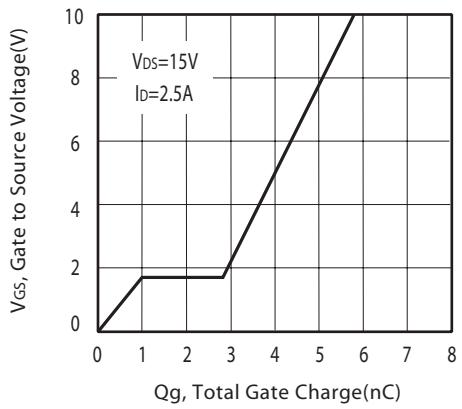
V_{SD}, Body Diode Forward Voltage(V)

Figure 8. Body Diode Forward Voltage Variation with Source Current



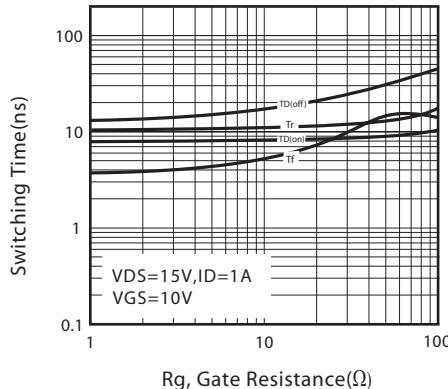
V_{DS}, Drain-to-Source Voltage(V)

Figure 9. Capacitance



Q_g , Total Gate Charge(nC)

Figure 10. Gate Charge



R_g, Gate Resistance(Ω)

Figure 11. switching characteristics

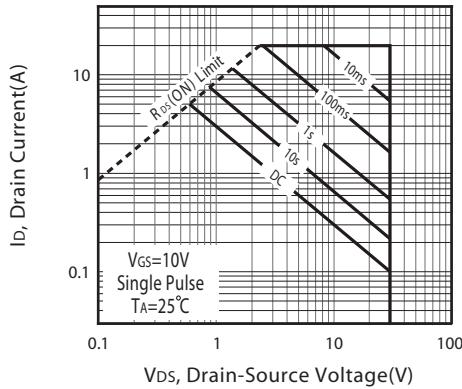
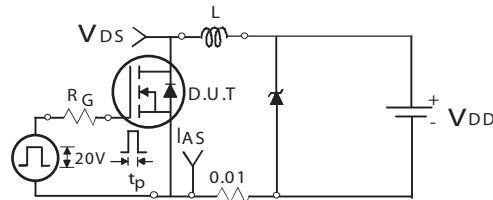


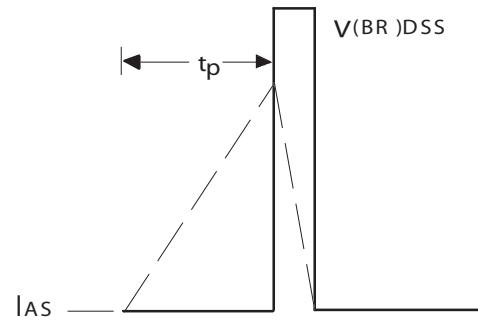
Figure 12. Maximum Safe Operating Area

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Unclamped Inductive Test Circuit

Figure 13a.



Unclamped Inductive Waveforms

Figure 13b.

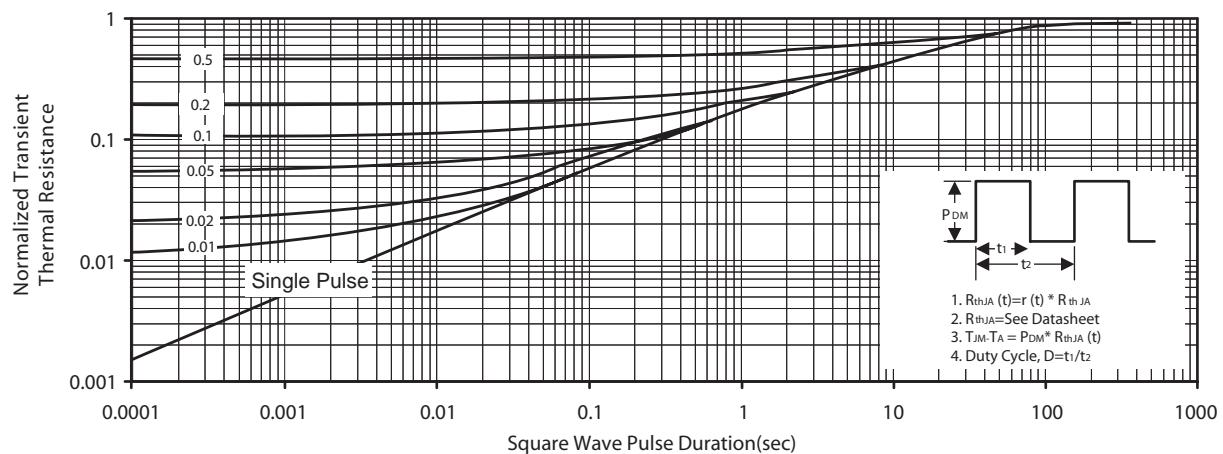
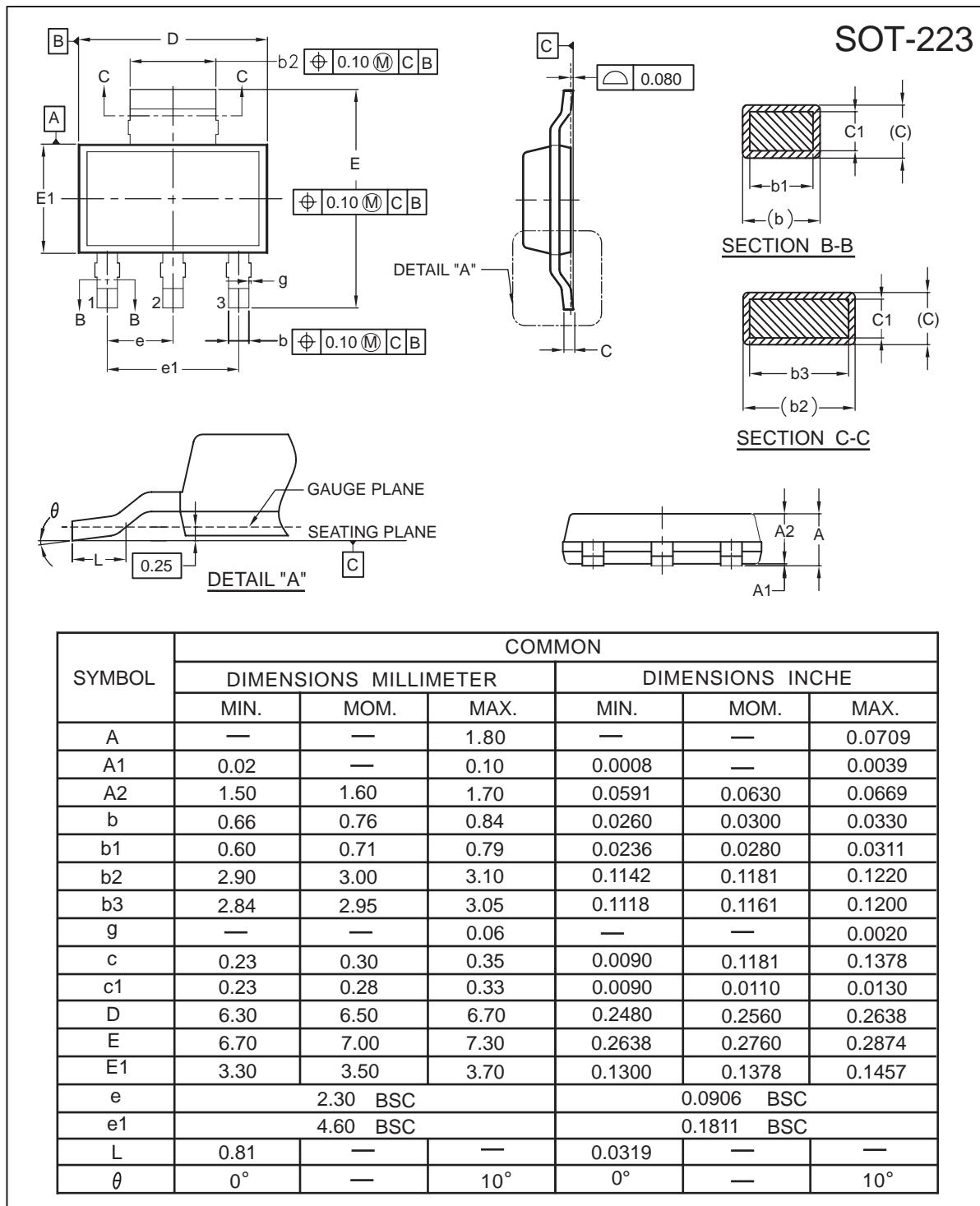


Figure 14. Normalized Thermal Transient Impedance Curve

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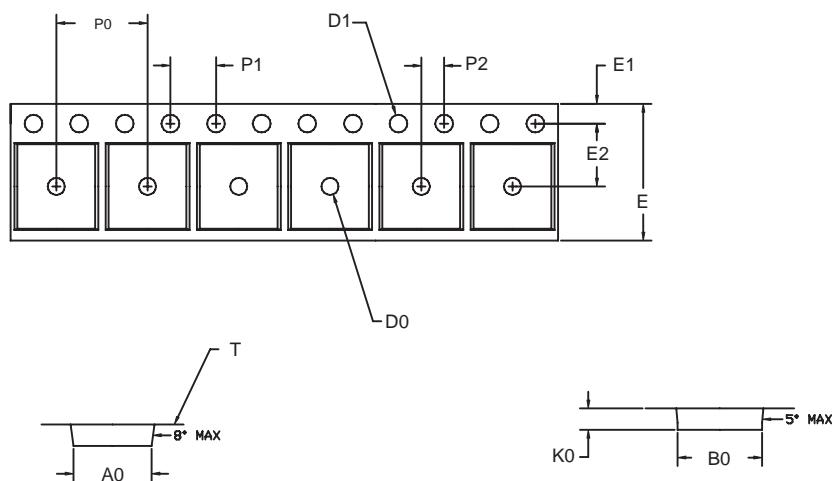
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SOT-223 Tape and Reel Data

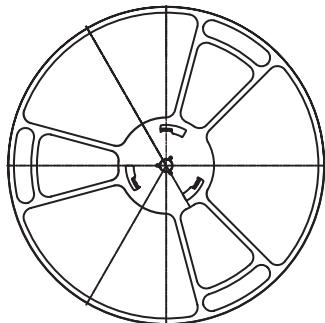
SOT-223 Carrier Tape



unit:mm

PACKAGE	A0	B0	K0	D0	D1	E	E1	E2	P0	P1	P2	T
---	6.83 ±0.1	7.42 ±0.1	1.88 ±0.1	1.50 + 0.25	1.60 + 0.1	12.0 + 0.3 - 0.1	1.75 ±0.1	5.50 ±0.5	8.0 ±0.1	4.00 ±0.1	2.00 ±0.05	0.292 ±0.02

SOT-223 Reel



UNIT:mm

REEL SIZE	M	N	W	W1	H	K	S	G	R	V
φ 330 ± 0.5	---	φ 97.0 ± 1.0	2.2	13.0 + 1.5	φ 13.0 + 0.5 - 0.2	10.6	2.0 ± 0.5	---	---	---